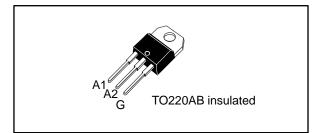


T835T-8I

8 A Snubberless™ Triac

Datasheet - production data



Features

- High static dV/dt
- High dynamic commutation
- 150 °C maximum T_j
- Three quadrants
- Built-in ceramic for tab insulation
- Compliance to UL1557 standard (ref : E81734)
- ECOPACK[®]2 compliant component
- Complies with UL94,V0
- Surge capability V_{DSM}, V_{RSM} = 900 V

Benefits

- Device is less likely to have false turn-on thanks to high dV/dt
- Better turn-off in high temperature environments thanks to (dl/dt)c
- Increase of thermal margin due to extended working T_j up to 150 °C
- Better thermal resistance due to the ceramic inside the package

Applications

- General purpose AC line load switching
- Motor control circuits
- Home appliances
- Heating
- Lighting
- Inrush current limiting circuits
- Overvoltage crowbar protection

DocID030985 Rev 2

1/10

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This is information on a product in full production.

Description

Available in through-hole package, the T835T-8I Triac can be used for the on/off or phase angle control function in general purpose AC switching where high commutation capability is required. This device can be used without a snubber RC circuit when the limits defined are respected.

TO-220AB insulated provides tab insulation, UL1557 certified, rated at 2.5 kV RMS and UL-94, V0 resin compliance.

Package environmentally friendly ECOPACK[®]2 graded (RoHS and Halogen Free compliance).

Snubberless[™] is a trademark of STMicroelectronics.

Figure 1: Functional diagram

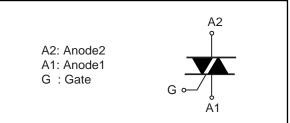


Table 1: Device summary

Symbol	Value	Unit
I _{T(RMS)}	8	А
Vdrm/Vrrm	800	V
V _{DSM} /V _{RSM}	900	V
IGT	35	mA

1 Characteristics

Table 2: Absolute maximum ratings (limiting values)

Symbol	Paran	Value	Unit		
I _{T(RMS)}	RMS on-state current (full sine wa	ave)	T _c = 118 °C	8	А
			t _p = 16.7 ms	63	А
ITSM			t _p = 20 ms	60	A
l ² t	$I^{2}t$ value for fusing, $t_{p} = 10 \text{ ms}$		T _j initial = 25 °C	24	A ² s
dl/dt	Critical rate of rise of on-state current, $I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$	T _j = 150 °C	f = 100 Hz	100	A/µs
	V _{DRM} /V _{RRM} Repetitive peak off-state voltage		T _j = 150 °C	600	V
V DRM/ V RRM			T _j = 125 °C	800	V
V _{DSM} /V _{RSM}	Non Repetitive peak off-state voltage		t _p = 10 ms	900	V
Ідм	Peak gate current	t _p = 20 μs	T _j = 150 °C	4	А
P _{G(AV)}	Average gate power dissipation	Average gate power dissipation $T_i = 150 \text{ °C}$			
T _{stg}	Storage junction temperature range	-40 to +150	°C		
Tj	Operating junction temperature ra	-40 to +150	°C		
ΤL	Maximum lead temperature for soldering during 10 s			260	°C
Vins	Insulation RMS voltage, 1 minute	UL1557 certif	ied (E81734)	2.5	kV

Table 3: Electrical characteristics (T_j = 25 °C, unless otherwise specified)

Symbol	Test Conditions		Value	Unit	
І _{бт} (1)	$V_D = 12 V, R_L = 30 \Omega$	1 - 11 - 111	Min.	1.75	mA
IGT ''	$V_D = 12 V, R_L = 30 \Omega$	1 - 11 - 111	Max.	35	mA
V _{GT}	V_D = 12 V, R _L = 30 Ω	1 - 11 - 111	Max.	1.3	V
Vgd	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, T_j = 150 \text{ °C}$	1 - 11 - 111	Min.	0.2	V
		I - III	Max.	60	mA
۱L	Ig = 1.2 x Igt	II	Max.	70	mA
Ін	I⊤ = 500 mA, gate open	Max.	40	mA	
d\ //dt	V _D = 536 V, gate open	T _j = 125 °C	Min.	2000	V/µs
07/01	dV/dt V _D = 402 V, gate open		iviiri.	1000	V/µs
(dl/dt)o		T _j = 125 °C	Min.	8	A/ms
(dl/dt)c	Without snubber, (dV/dt)c > 20 V/µs	T _j = 150 °C		4	A/ms

Notes:

 $^{(1)}\mbox{For both polarities of A2 referenced to A1.}$



Characteristics

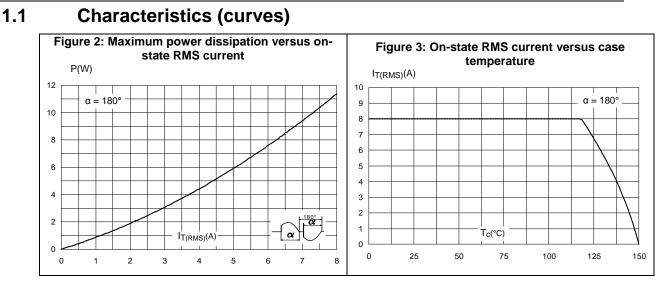
				Ollaraol		
	Table 4: Static characteristics					
Symbol	Test conditions	Tj		Value	Unit	
Vtm ⁽¹⁾	$I_T = 11.3 \text{ A}, t_p = 380 \ \mu \text{s}$	25 °C	Max.	1.60	V	
Vto	Threshold on-state voltage	150 °C	Max.	0.87	V	
RD	Dynamic resistance	150 °C	Max.	80	mΩ	
Idrm/Irrm	VDRM = VRRM = 800 V	25 °C	Max.	5	μA	
	$\nabla DRM = \nabla RRM = 8000 \nabla$	125°C	IVIAX.	1.0	mA	
	$V_{\text{DRM}} = V_{\text{RRM}} = 600 \text{ V}$	150 °C	Max.	2.5	mA	

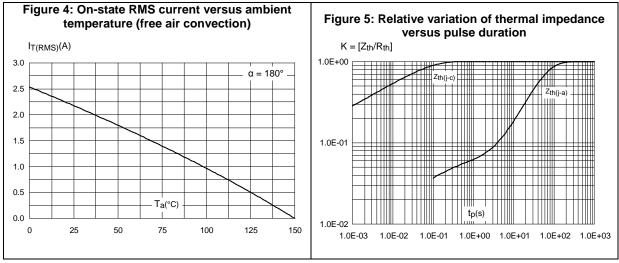
Notes:

 $^{(1)}\mbox{For both polarities of A2 referenced to A1.}$

Symbo	ol	Parameter	Value	Unit	
Rth(j-c))	Junction to case (AC) Max.		2.8	°C ///
R _{th(j-a)})	Junction to ambient	Тур.	60	°C/W







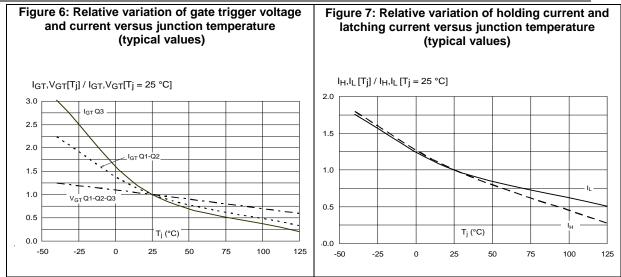
4/10

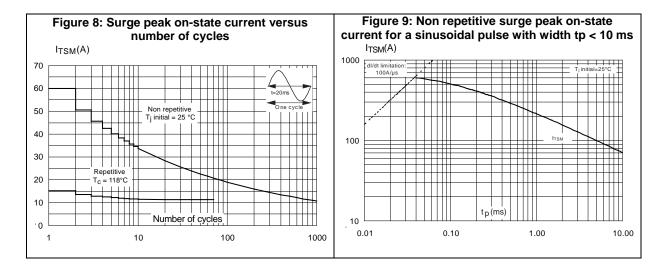
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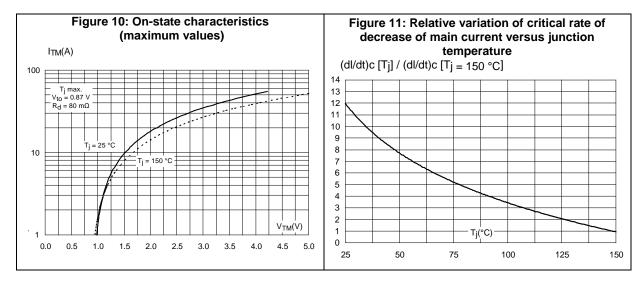




Characteristics







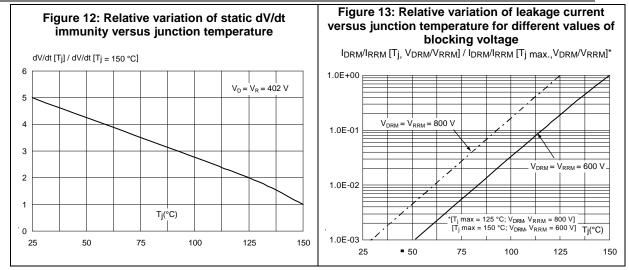
DocID030985 Rev 2

5/10

51

Characteristics

T835T-8I



6/10

DocID030985 Rev 2

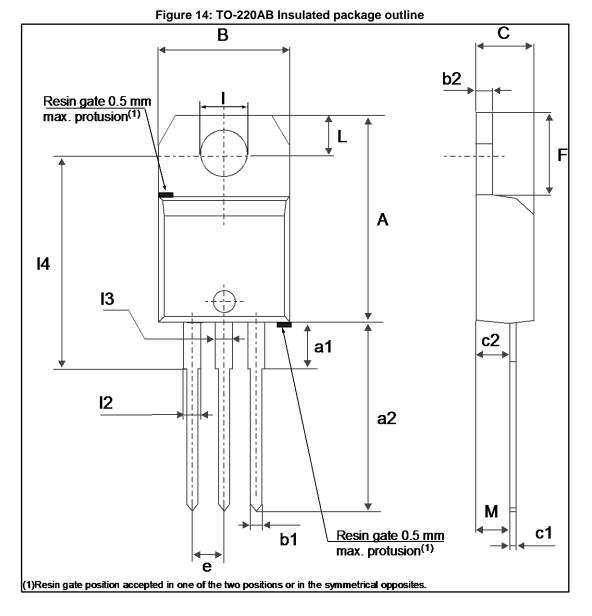


2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

- ECOPACK[®]2 (Lead-free plating and Halogen free package compliance)
- Lead-free package leads finishing
- Halogen-free molding compound resin meets UL94 standard level V0.
- Recommended torque (for through-hole package): 0.4 to 0.6 N·m

2.1 TO-220AB Insulated package information



57

DocID030985 Rev 2

Package information

	Table 6: TO-220AB Insulated package mechanical data						
		Dimensions					
Ref.		Millimeters		Inches ⁽¹⁾			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	15.20		15.90	0.5984		0.6260	
a1		3.75			0.1476		
a2	13.00		14.00	0.5118		0.5512	
В	10.00		10.40	0.3937		0.4094	
b1	0.61		0.88	0.0240		0.0346	
b2	1.23		1.32	0.0484		0.0520	
С	4.40		4.60	0.1732		0.1811	
c1	0.49		0.70	0.0193		0.0276	
c2	2.40		2.72	0.0945		0.1071	
е	2.40		2.70	0.0945		0.1063	
F	6.20		6.60	0.2441		0.2598	
I	3.73		3.88	0.1469		0.1528	
L	2.65		2.95	0.1043		0.1161	
12	1.14		1.70	0.0449		0.0669	
13	1.14		1.70	0.0449		0.0669	
14	15.80	16.40	16.80	0.6220	0.6457	0.6614	
М		2.6			0.1024		

Notes:

 $\ensuremath{^{(1)}}\xspace$ Inch dimensions are for reference only.

8/10



3 Ordering in

T835T-8I

Ordering information

Figure 15: Ordering information scheme				
<u>Series</u> T = Triac RMS current	T 8 35 T - 8 I			
8 = 8 A I _{GT} current				
35 = 35 mA Specific application				
T = increased (dl/dt) and dV/dt provide Voltage	oducing reduced I _{TSM}			
8 = 800 V				
Package I = TO-220AB insulated tab				

Table 7: Ordering information

rabie i rendering merination					
Order code	Marking	Package	Weight	Base qty.	Delivery mode
T835T-8I	T835T-8I	TO-220AB insulated	2.3 g	50	Tube

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
17-Oct-2017	1	Initial release.
06-Nov-2017	2	Updated Table 4: "Static characteristics".



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